

IN THE SPECIFICATION

Please insert as a separate paragraph below the title on page 1 – This is a division of Application No. 09/191,729, filed November 13, 1998 – therein.

IN THE CLAIMS

Please cancel claim 13 without prejudice.

Please enter the following claim:

C1 Sub D1

8. (Twice Amended) A gate electrode comprising:
a gate layer disposed above a substrate;
thin first spacers disposed adjacent to opposite sides of said gate layer
wherein said thin first spacers have approximately the same height as said gate
layer;
thick second spacers disposed adjacent to each of said thin first
spacers, said thick second spacers comprising nitride, wherein said thick
second spacers have approximately the same height as said gate layer; and
a conductive layer disposed over said gate layer, said conductive layer
extending beyond edges of said gate layer.
